

2N1613
2N1711
2N1893

NPN Silicon Transistor
JEDEC TO-39 case

DESCRIPTION

2N1613, 2N1711, and 2N1893 are Silicon NPN Planar Epitaxial Transistors designed for small signal general purpose and switching applications.

MAXIMUM RATINGS ($T_A=25^{\circ}\text{C}$ unless otherwise noted)

| | | 2N1613 | 2N1711 | 2N1893 | |
|---|----------------|--------------------------------|--------|--------|-------|
| Collector-Base Voltage | V_{CB0} | 75 | 75 | 120 | Vdc |
| Collector-Emitter Voltage | V_{CE0} | - | - | 80 | Vdc |
| Collector-Emitter Voltage | V_{CER} | 50 | 50 | 100 | Vdc |
| Emitter-Base Voltage | V_{EB0} | 7.0 | 7.0 | 7.0 | Vdc |
| Collector Current-Continuous | I_C | | 500 | | mA |
| Power Dissipation | PT | | 0.8 | | watts |
| Power Dissipation, $T_C=25^{\circ}\text{C}$ | PT | | 3.0 | | watts |
| Operating and Storage | T_J, T_{stg} | -65 to +200 $^{\circ}\text{C}$ | | | |
| Junction Temperature | | | | | |

ELECTRICAL CHARACTERISTICS ($T_A=25^{\circ}\text{C}$)

| Symbol | Test Conditions | 2N1613 | | 2N1711 | | 2N1893 | | Unit |
|-------------|--|--------|-----|--------|-----|--------|-----|------|
| | | Min | Max | Min | Max | Min | Max | |
| I_{CBO} | $V_{CB}=60\text{V}$ | | 10 | | 10 | | - | nA |
| I_{CBO} | $V_{CB}=90\text{V}$ | | - | | - | | 10 | nA |
| I_{EBO} | $V_{EB}=5.0\text{V}$ | | 10 | | 5 | | 10 | nA |
| BV_{CB0} | $I_C=100\mu\text{A}$ | 75 | | 75 | | 120 | | V |
| BV_{CE0} | $I_C=10\text{mA}$ | | | | | 80 | | V |
| BV_{CER} | $I_C=10\text{mA}, R_{BE}=10\ \Omega$ | 50 | | 50 | | 100 | | V |
| BV_{EB0} | $I_E=100\mu\text{A}$ | 7.0 | | 7.0 | | 7.0 | | V |
| $V_{CE}(s)$ | $I_C=50\text{mA}, I_B=5\text{mA}$ | | - | | - | | 1.2 | V |
| $V_{CE}(s)$ | $I_C=150\text{mA}, I_B=15\text{mA}$ | | 1.5 | | 1.5 | | 5.0 | V |
| $V_{BE}(s)$ | $I_C=50\text{mA}, I_B=5\text{mA}$ | | - | | - | | 0.9 | V |
| $V_{BE}(s)$ | $I_C=150\text{mA}, I_B=15\text{mA}$ | | 1.3 | | 1.3 | | 1.3 | V |
| h_{FE} | $V_{CE}=10\text{V}, I_C=10\mu\text{A}$ | | - | 20 | | | - | - |
| h_{FE} | $V_{CE}=10\text{V}, I_C=100\mu\text{A}$ | 20 | | 35 | | 20 | | - |
| h_{FE} | $V_{CE}=10\text{V}, I_C=10\text{mA}$ | 35 | | 75 | | 35 | | - |
| h_{FE} | $V_{CE}=10\text{V}, I_C=150\text{mA}$ | 40 | 120 | 100 | 300 | 40 | 120 | - |
| h_{FE} | $V_{CE}=10\text{V}, I_C=500\text{mA}$ | 20 | | 40 | | - | | - |
| f_T | $V_{CE}=10\text{V}, 50\text{mA}, f=20\ \text{MHz}$ | 60 | | 70 | | 50 | | MHz |
| C_{ob} | $V_{CB}=10\text{V}, f=100\ \text{KHz}$ | | 25 | | 25 | | 15 | pF |
| C_{ib} | $V_{BE}=0.5\text{V}, f=100\ \text{KHz}$ | | 80 | | 80 | | 85 | pF |
| NF | $V_{CE}=10\text{V}, I_C=300\mu\text{A}, f=1.0\ \text{KHz}$ | | 12 | | 8.0 | | - | dB |

